## IN THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

- 1. (Currently amended) A light emitting element <u>comprising</u>: in which an organic compound film comprising a hole transporting material, an electron transporting material, a first impurity, and a second impurity is provided between an anode and a cathode, being characterized in that wherein the organic compound film is laminated with a first mixed region comprising the hole transporting material and the first impurity, a hole transporting region comprising the hole transporting material, a second mixed region comprising the electron transporting material and the second impurity, and an electron transporting region comprising the electron transporting material in order from a side of the anode.
- 2. (Currently amended) A light emitting element, according to claim 1, being characterized in that wherein the first impurity and the second impurity comprise a coloring material.
- 3. (Currently amended) A light emitting element, according to claim 1, being characterized in that wherein a ratio of a film thickness of the hole transporting region to a total film thickness of the first mixed region and the hole transporting region is 10% or more.
- 4. (Currently amended) A light emitting element, according to claim 1, being characterized in that wherein a concentration of the first impurity in the first mix region is in the range of from 0.1% by weight to 10% by weight.

- 5. (Currently amended) A light emitting element, according to claim 1, being characterized in that wherein the light emitting element is mounted in an electronic apparatus selected from the group consisting of a video camera, a digital camera, a head mount display, a car navigation system, a projector, a personal computer, and a portable information terminal.
- 6. (Currently amended) A method for manufacturing a light emitting element in which an organic compound film comprising a hole transporting material, an electron transporting material, a first impurity and a second impurity is provided between an anode and a cathode, comprising, in the organic compound film, being characterized that the method comprises comprising the steps of:

forming a first mixed region comprising the hole transporting material and the first impurity on the anode;

forming a hole transporting region comprising the hole transporting material on the first mixed region;

forming a second mixed region comprising the electron transporting material and the second impurity on the hole transporting region; and

forming an electron transporting region comprising the electron transporting material on the second mixed region.

7. (Currently amended) A method for manufacturing a light emitting element according to claim 6, being characterized in that wherein the first impurity and the second impurity comprise a coloring material.

- 8. (Currently amended) A method for manufacturing a light emitting element according to claim 6, being characterized in that wherein a ratio of a film thickness of the hole transporting region to a total film thickness of the first mixed region and the hole transporting region is 10% or more.
- 9. (Currently amended) A method for manufacturing a light emitting element according to claim 6, being characterized in that wherein a concentration of the first impurity in the first mix region is in the range of from 0.1% by weight to 10% by weight.
- 10. (Currently amended) A method for manufacturing a light emitting element according to claim 6, being characterized in that wherein the light emitting element is mounted in an electronic apparatus selected from the group consisting of a video camera, a digital camera, a head mount display, a car navigation system, a projector, a personal computer, and a portable information terminal.
- 11. (Currently amended) A light emitting device having a light emitting element being characterized in that, the light emitting element comprises comprising: an anode; a first organic compound layer comprising a hole transporting material and a first impurity on the anode; a second organic compound layer essentially consisting of a hole transporting material on the first organic compound layer; a third organic compound layer comprising an electron transporting material and a second impurity on the second organic compound layer; a fourth organic compound layer essentially consisting of the electron transporting material on the third organic compound layer; and a cathode on the fourth organic compound layer.

- 12. (Currently amended) A light emitting element, according to claim 11, being characterized in that wherein the first impurity and the second impurity comprise a coloring material.
- 13. (Currently amended) A light emitting element, according to claim 11, being characterized in that wherein a ratio of a film thickness of the hole transporting region to a total film thickness of the first mixed region and the hole transporting region is 10% or more.
- 14. (Currently amended) A light emitting element, according to claim 11, being characterized in that wherein a concentration of the first impurity in the first mix region is in the range of from 0.1% by weight to 10% by weight.
- 15. (Currently amended) A light emitting element, according to claim 11, being characterized in that wherein the light emitting element is mounted in an electronic apparatus selected from the group consisting of a video camera, a digital camera, a head mount display, a car navigation system, a projector, a personal computer, and a portable information terminal.
- 16. (Currently amended) A light emitting device being characterized by comprising: an anode; a first organic compound layer comprising a hole transporting material and a first impurity on the anode; a second organic compound layer essentially consisting of a hole transporting material on the first organic compound layer; a third organic compound layer comprising an electron transporting material and a second impurity on the second organic compound layer; a fourth organic compound

layer essentially consisting of the electron transporting material on the third organic compound layer; and a cathode on the fourth organic compound layer.

- 17. (Currently amended) A light emitting element, according to claim 16, being characterized in that wherein the first impurity and the second impurity comprise a coloring material.
- 18. (Currently amended) A light emitting element, according to claim 16, being characterized in that wherein a ratio of a film thickness of the hole transporting region to a total film thickness of the first mixed region and the hole transporting region is 10% or more.
- 19. (Currently amended) A light emitting element, according to claim 16, being characterized in that wherein a concentration of the first impurity in the first mix region is in the range of from 0.1% by weight to 10% by weight.
- 20. (Currently amended) A light emitting element, according to claim 16, being characterized in that wherein the light emitting element is mounted in an electronic apparatus selected from the group consisting of a video camera, a digital camera, a head mount display, a car navigation system, a projector, a personal computer, and a portable information terminal.
- 21. (Currently amended) A method for manufacturing a light emitting device being characterized by comprising the steps of:

forming a first organic compound layer comprising a hole transporting material and a first

impurity on the anode;

forming a second organic compound layer essentially consisting of a hole transporting material on the first organic compound layer;

forming a third organic compound layer comprising an electron transporting material and a second impurity on the second organic compound layer;

forming a fourth organic compound layer essentially consisting of the electron transporting material on the third organic compound layer; and

forming a cathode on the fourth organic compound layer.

- 22. (Currently amended) A method for manufacturing a light emitting element according to claim 21, being characterized in that wherein the first impurity and the second impurity comprise a coloring material.
- 23. (Currently amended) A method for manufacturing a light emitting element according to claim 21, being characterized in that wherein a ratio of a film thickness of the hole transporting region to a total film thickness of the first mixed region and the hole transporting region is 10% or more.
- 24. (Currently amended) A method for manufacturing a light emitting element according to claim 21, being characterized in that wherein a concentration of the first impurity in the first mix region is in the range of from 0.1% by weight to 10% by weight.

25. (Currently amended) A method for manufacturing a light emitting element according to claim 21, being characterized in that wherein the light emitting element is mounted in an electronic apparatus selected from the group consisting of a video camera, a digital camera, a head mount display, a car navigation system, a projector, a personal computer, and a portable information terminal.